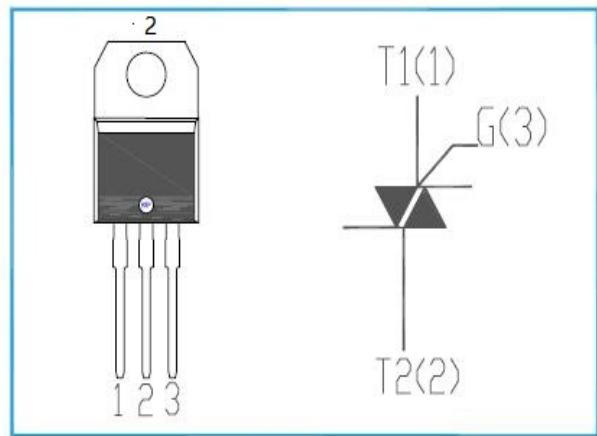


Features:

- * NPNPN Bi-direction Triac
- * Back multilayer metal electrode
- * High temperature reliability
- * Glass Passivated junction chips

Application:

Power tool ,moto speed controller,Vacuum cleaner, heating temperature controller,Solid state relay and phase control circuits.



Maximum Ratings and Electrical Characteristics

Symbol	Absolute maximum ratings parameters	Value	Unit
$I_{T(RMS)}$	RMS on-state current	16	A
I_{TSM}	Non repetitive surge peak on-state current	160	A
I^2t	I^2t value for fusing	144	A ² s
di/dt	Critical rate of rise of on-state current	50	A/us
V_{DRM}/V_{RRM}	Non repetitive surge peak off-state voltage	800	V
I_{GM}	Peak gate current	4	A
$P_{G(AV)}$	Average gate power dissipation	1	W
T_{stg}	Storage junction temperature range	-40 °C ~ +150 °C	°C
T_j	Operating junction temperature range	-40 °C + 125 °C	°C

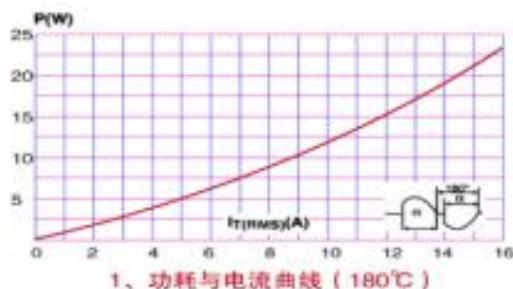
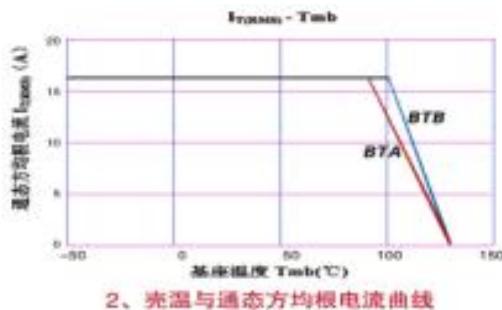
Electrical Characteristics(4 quadrant) ($T_j=25^\circ C$, unless otherwise specified)

Symbol	Test Condition	Quadrant		Value		Unit
I_{GT}	$V_D=12V \ R_L=100\Omega$	I II III IV	MAX	I	II III	IV
				10	25	mA
			MAX	1.5		V
V_{GD}	$T_j=125^\circ C$		MIN	0.2		V
I_H	$I_T=0.5A$		MAX	60		mA
I_L	$I_G=1.2I_{GT}$		MAX	60		mA
				100		
dv/dt	$V_D=2/3V_{DRM} \ T_j=125^\circ C$		MIN	500		V/us
$(dv/dt)c$	$T_j=125^\circ C$		MIN	10		V/us

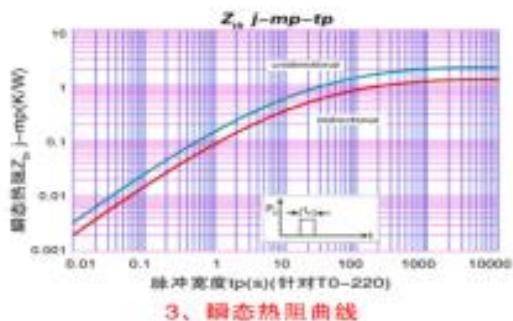
Static Characteristics

Symbol	Test Condition			Value	Unit
V_{TM}	$I_{TM}=32A$	$T_j=25^\circ C$	MAX	1.5	V
V_{T0}	Threshold voltage	$T_j=125^\circ C$	MAX	0.87	V
R_d	Dynamic resistance	$T_j=125^\circ C$	MAX	14.6	mΩ
I_{DRM} I_{RRM}	$V_{DRM} = V_{RRM}$	$T_j=25^\circ C$ $T_j=125^\circ C$	MAX	5	uA
				1	mA
$R_{th(j-c)}$	Junction to case (AC)			2.1	°C/W

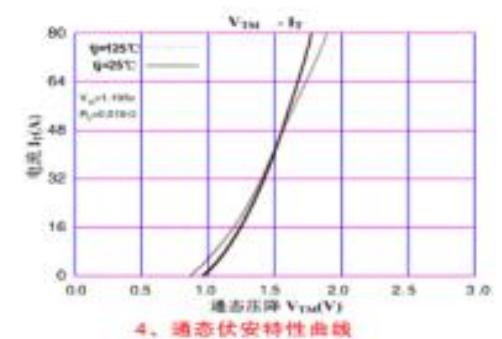
● Typical Characteristics

1. 功耗与电流曲线 (180°C)

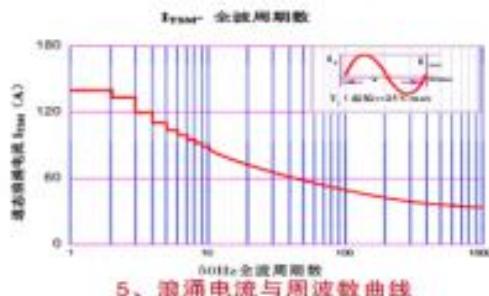
2. 壳温与通态方均根电流曲线



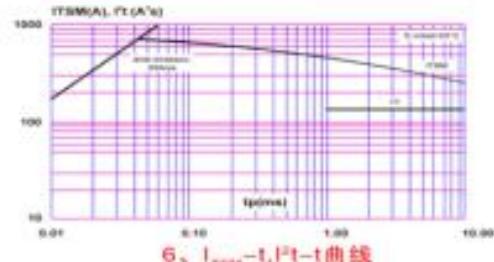
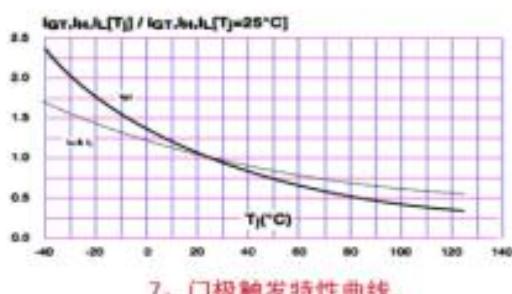
3. 铜态热阻曲线



4. 通态伏安特性曲线



5. 波涌电流与周期数曲线

6. $I_T-S-I_T^2-t$ 曲线

7. 门极触发特性曲线

- TO-220 Dimensions

